

ID	R <sub>Ds</sub> (ON)(Typ)	VDSS	
10A	0.66Ω	500V	

## Applications:

- Switch Mode Power Supply(SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)

#### Features:

- Fast switching speed
- 100% avalanche tested
- Improved dv/dt capability

# 

### **Ordering Information**

Part Number	Package	Marking	Packing	Qty.
RS10N50F	T0-220F	RS10N50F	Tube	50 PCS

### Absolute Maximun Ratings Tc= $25^{\circ}$ C unless otherwise specified

Symbol	Parameter	RS10N50F	Units
VDSS	Drain-to-Source Voltage	500	V
ID	Continuous Drain Current TC=25 $^{\circ}$ C	10	٨
IDM	Pulsed Drain Current (Note*1)	40	A
PD	Power Dissipation	40	W
VGS	Gate- to- Source Voltage	±30	V
EAS	Single Pulse Avalanche Engergy L = 10mH, VDD = 50V, RG = 25 Ω	215	mJ
	Maximum Temperature for Soldering		
TL TPKG	Leads at 0.063in(1.6mm)from Case for 10 seconds Package Body for 10 seconds	300 260	°C
TJ and TSTG	Operating Junction and Storage Temperature Range	-55 to 150	

\* Drain Current Limited by Maximum Junction Temperature

Caution: Stresses greater than those listed in the" Absolute Maximum Ratings" Table may cause permanent damage to the device.



# **Thermal Resistance**

Symbol	Parameter	RS10N50F	Units	Test Conditions
RθJC	Junction-to-Case	3.13	°C/W	Drain lead soldered to water cooled heatsink, PD adjusted for a peak junction temperature of + 1 5 0 $^\circ\!\!C$
RθJA	Junction-to- Ambient	62.5		1 cubic foot chamber,free air.

## **OFF Characteristics** TJ= $25^{\circ}$ C unless otherwise specified

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
BVDSS	Drain- to- source Breakdown Voltage	500			V	VGS=0V,ID=250μ Α
IDSS	Drain- to- Source Leakage Current			1	μA	VDS=500V,VGS= 0V
	Gate- to- Source Forward Leakage			100	nA	VGS=30V ,VDS=0 V
IGSS	Gate- to- Source Reverse Leakage			-100		VGS=-30V ,VDS= 0V

# **ON Characteristics** TJ=25°C unless otherwise specified

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
RDS(on)	Static Drain- to- Source On- Resistance(Note*2)		0.66	0.8	Ω	VGS=10V,ID=5A
VGS(TH )	Gate Threshold Voltage	3		4	V	VGS=VDS,ID=25 0μA

## **Resistive Switching Characteristics** Essentially independent of operating temperature

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
td(ON)	Turn- on Delay Time		22		nS	VDS=250V ID=10A RG=25Ω
trise	Rise Time		39			
td(OFF)	Turn- OFF Delay Time		116			
tfall	Fall Time		12			



Symbol	Parameter	Min.	Тур.	Max.	Units	<b>Test Conditions</b>
Ciss	Input Capacitance		1090			VGS=0V VDS=25V f=1.0MHz
Coss	Output Capacitance		120		pF	
Crss	Reverse Transfer Capacitance		12			
Qg	Total Gate Charge		32			VDS=400V
Qgs	Gate- to- Source Charge		6		nC	ID=10A VGS=10V
Qgd	Gate-to-Drain(" Miller") Charge		16			

#### **Dynamic Characteristics** Essentially independent of operating temperature

### **Source- Drain Diode Characteristics**

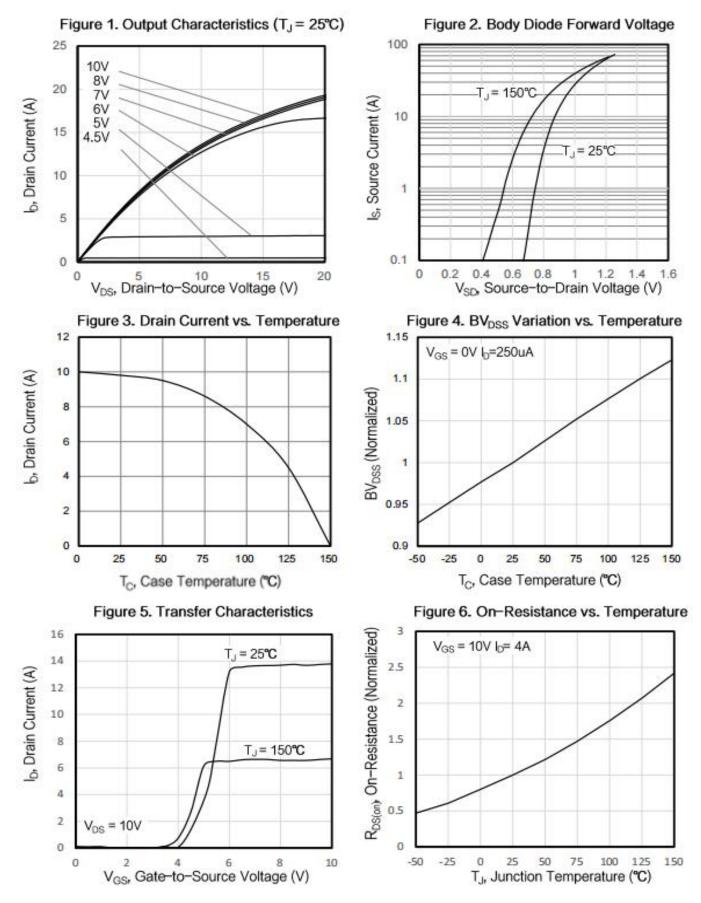
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
IS	Continuous Source Current			10	А	Integral pn- diode
ISM	Maximum Pulsed Current			40	А	in MOSFET
VSD	Diode Forward Voltage			1.4	V	IS=5A,VGS=0V
trr	Reverse Recovery Time		480		nS	VGS=0V
Qrr	Reverse Recovery Charge		2.1		μC	IS=10A,di/dt=100 A/µs

#### Notes:

- \* 1. Repetitive rating, pulse width limited by maximum junction temperature.
- \* 2. Pulse Test: Pulse width  $\leq$  300µs, Duty Cycle  $\leq$  1%

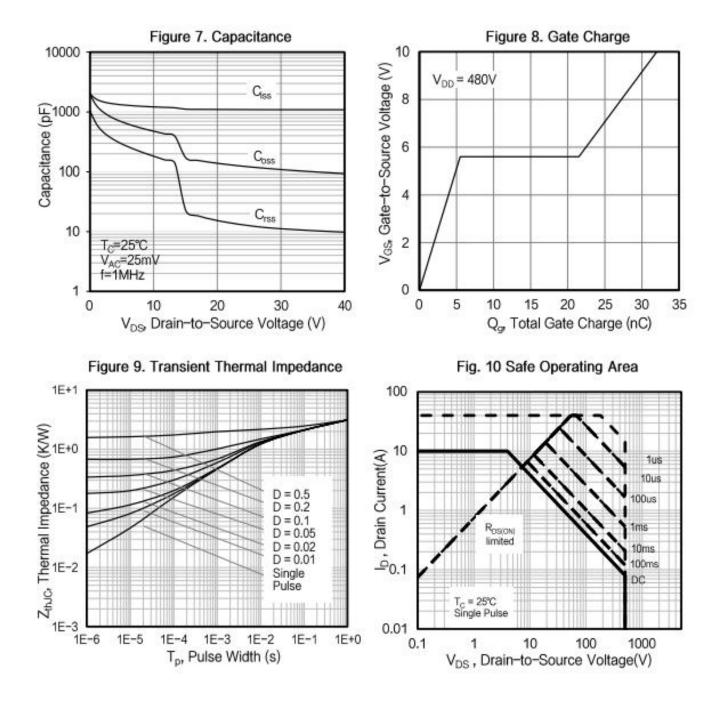


## **Typical Feature Curve**



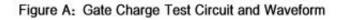
REV:K-B03-05-2024 www.reasunos.com







## **Test Circuits and Waveforms**



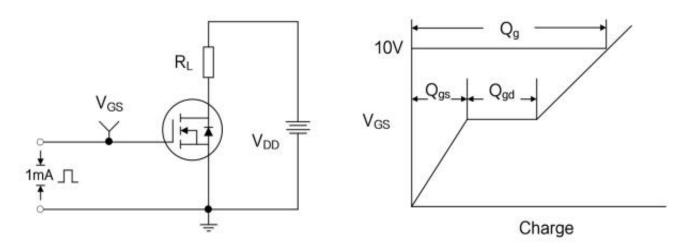


Figure B: Resistive Switching Test Circuit and Waveform

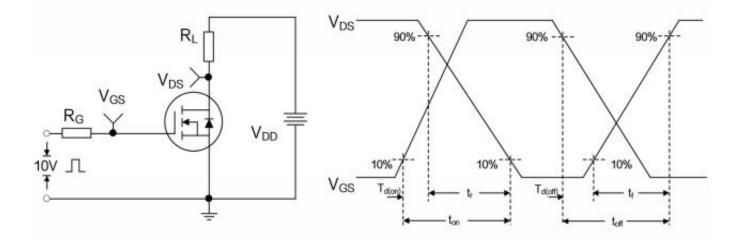
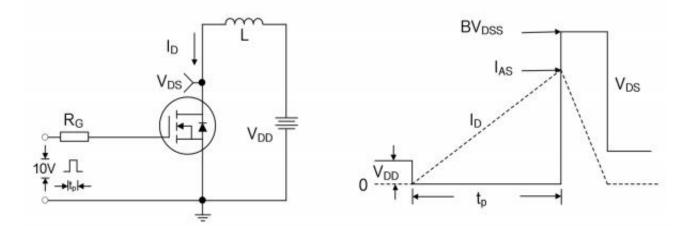
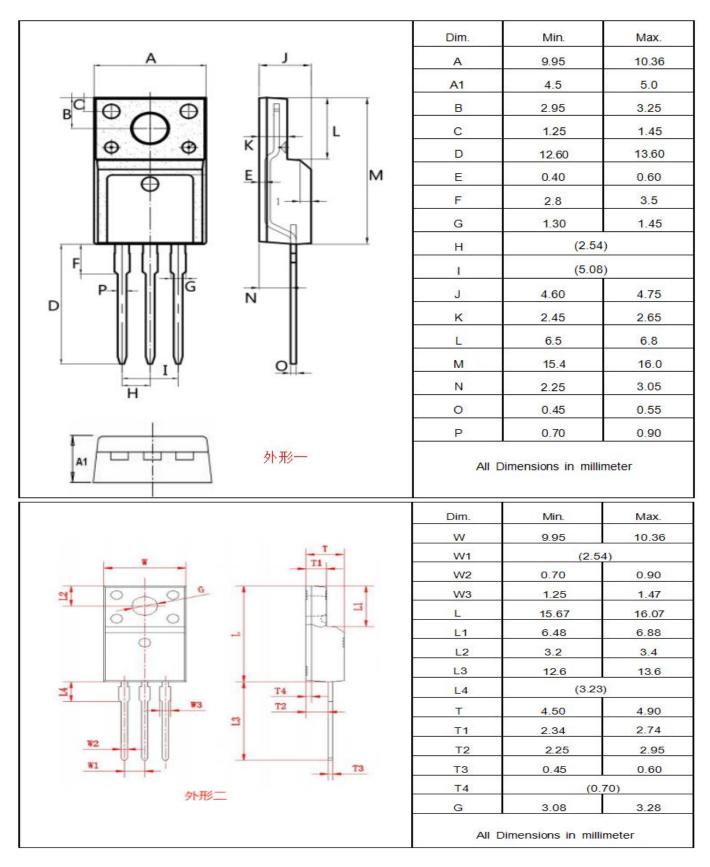


Figure C: Unclamped Inductive Switching Test Circuit and Waveform





# Package outline drawing(TO-220F Unit: mm)





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